



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

Variation	Page)	I _D
V _{(BR)DSS}	R _{DS(on)}	$T_A = +25^{\circ}C$
2017	3.0Ω @ V _{GS} = 4.5V	240mA
20V	6.0Ω @ V _{GS} = 1.8V	180mA

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions

Features

- Dual N-Channel MOSFET
- Low On-Resistance:
 - 3.0Ω @ 4.5V
 - 4.0Ω @ 2.5V
 - 6.0Ω @ 1.8V
- 10Ω @ 1.5V
- Very Low Gate Threshold Voltage, 1.05V Max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package
- ESD Protected Gate (HBM 300V)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

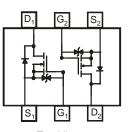
Mechanical Data

- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (@)
- Weight: 0.0027 grams (Approximate)



ESD PROTECTE





Top View Schematic and Transistor Diagram

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN26D0UDJ-7	SOT963	10,000/Tape & Reel

Notes:

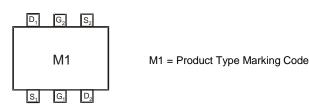
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information (Note 5)



Note: 5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±10	V
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	240 190	mA
Continuous Drain Current (Note 6) V _{GS} = 1.8V	Steady State	T _A = +25°C T _A = +70°C	ID	180 140	mA
Pulsed Drain Current - $T_P = 10\mu s$	I _{DM}	805	mA		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	409	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20		_	V	$V_{GS} = 0V, I_D = 100 \mu A$	
Zero Gate Voltage Drain Current @ T _J = +25°C	Inco			500	nA	$V_{DS} = 20V, V_{GS} = 0V$	
@T _J = +85°C (Note 8)	IDSS			1.7	μA	$V_{DS} = 2.6V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}			±1	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
	IGSS			±100	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)			-				
Gate Threshold Voltage	V _{GS(th)}	0.45	0.8	1.05	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	1.8	3.0		$V_{GS} = 4.5V, I_D = 100mA$	
			2.5	4.0	Ω	$V_{GS} = 2.5V, I_D = 50mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}		3.4	6.0		$V_{GS} = 1.8V, I_D = 20mA$	
			4.7	10.0		$V_{GS} = 1.5V, I_D = 10mA$	
			9.5	_		$V_{GS} = 1.2V, I_{D} = 1mA$	
Forward Transconductance	Y _{fs}	180	240	_	mS	$V_{DS} = 10V, I_D = 0.1A$	
Source-Drain Diode Forward Voltage		0.5	0.8	1.0	V	$V_{GS} = 0V, I_{S} = 10mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	14.1	_	pF	V _{DS} = 15V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss		2.9	_	pF		
Reverse Transfer Capacitance	Crss	_	1.6	_	pF		
SWITCHING CHARACTERISTICS, V _{GS} = 4.5V (Note 8)							
Turn-On Delay Time	t _{d(on)}		3.8				
Rise Time	t_r — 7.9 — $V_{GS} = 4.5V$		$V_{GS} = 4.5V, V_{DD} = 10V$				
Turn-Off Delay Time			$I_D = 200 \text{mA}, R_G = 2.0 \Omega$				
Fall Time	t _f		15.2				

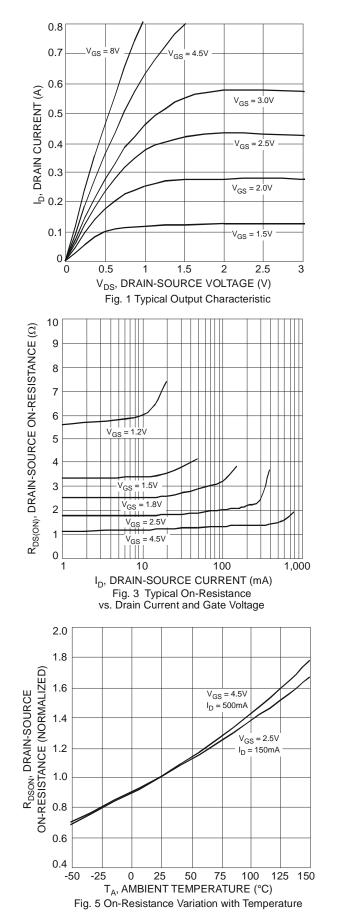
Notes: 6. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch with minimum recommended pad layout; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

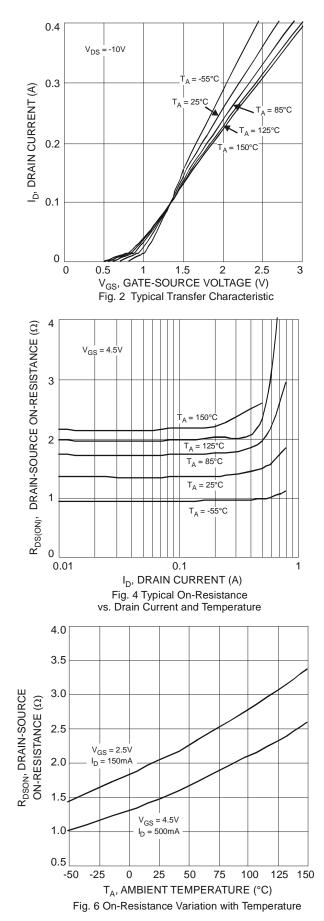
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design, not subject to production testing.

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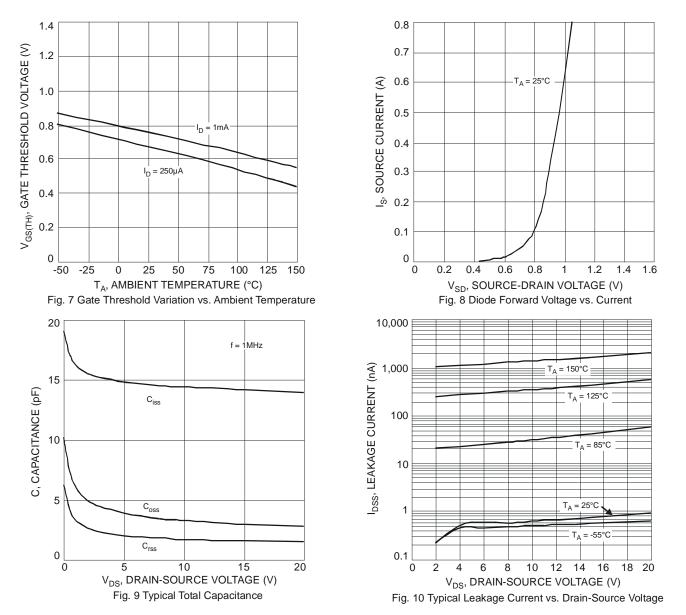






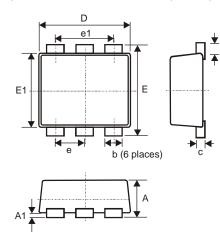
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Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

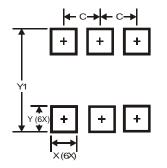


SOT963					
Dim	Min	Max	Тур		
Α	0.40	0.50	0.45		
A1	0	0.05	-		
С	0.120	0.180	0.150		
D	0.95	1.05	1.00		
Е	0.95	1.05	1.00		
E1	0.75	0.85	0.80		
L	0.05	0.15	0.10		
b	0.10	0.20	0.15		
е	0.35 Typ				
e1	0.70 Тур				
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.350
Х	0.200
Y	0.200
Y1	1.100

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